



A275308

Preliminary

32K X 8 OTP CMOS EPROM

Document Title

32K X 8 OTP CMOS EPROM

Revision History

<u>Rev. No.</u>	<u>History</u>	<u>Issue Date</u>	<u>Remark</u>
0.0	Initial issue	April 22, 1998	Preliminary
0.1	Error correction : In program verify mode, change CEB= V_{IH} to CEB= V_{IL}	June 03, 1998	
1.0	Change \overline{CE} from V_{IL} to V_{IH} during program verify mode	July 27, 1998	
2.0	Change program verify mode VCC from 6.25V to VCC Delete 55 ns specification	November 16, 1998	



Preliminary

32K X 8 OTP CMOS EPROM

Features

- 32,768 X 8 bit organization
- Programming voltage: 12.75V
- Access time: 70/90 ns (max.)
- Current: Operating: 30mA (max.) at 5MHz
Standby: 100µA (max.)

- All inputs and outputs are directly TTL-compatible
- Available in 28-pin DIP and 32-PLCC packages

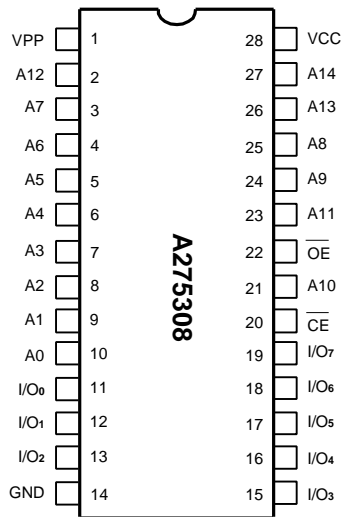
General Description

The A275308 chip is a high-performance 262,144 bit one-time programmable read only memory (OTP EPROM) organized as 32K by 8 bits. The A275308 requires only 5V power supply in normal read mode

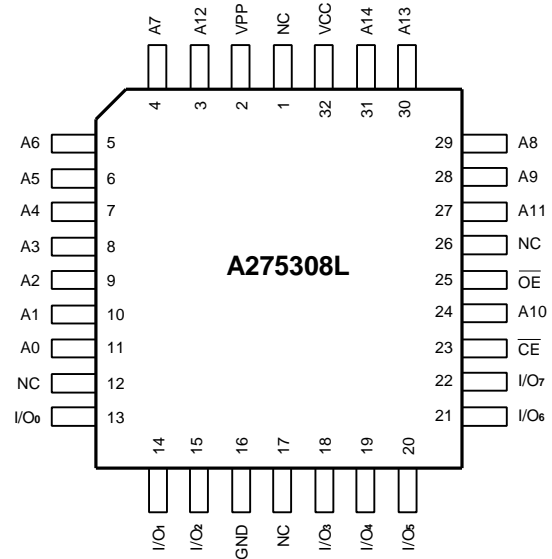
operation and any input signals are TTL levels. The A275308 is available in industry standard 28 pin dual-in-line and 32 lead PLCC packages.

Pin Configurations

■ **DIP**



■ **PLCC**



Pin Configurations

Pin Name	Function
A0-A14	Address Inputs
I/O ₇ -I/O ₀	Data Inputs / Outputs
$\overline{\text{CE}}$	Chip Enable
$\overline{\text{OE}}$	Output Enable
NC	No Internal Connection
VPP	Program Power Supply
VCC	Power Supply
GND	Ground

Operating Modes and Truth Table

Mode	$\overline{\text{CE}}$	$\overline{\text{OE}}$	A0	A1	A9	VPP	VCC	I/O ₇ -I/O ₀
Read	V _{IL}	V _{IL}	X	X	X	VCC	VCC	Data Out
Output Disable	V _{IL}	V _{IH}	X	X	X	VCC	VCC	Hi-Z
Standby	V _{IH}	X	X	X	X	VCC	VCC	Hi-Z
Program	V _{IL}	V _{IH}	X	X	X	12.75V	6.25V	Data In
Program Verify	V _{IH}	V _{IL}	X	X	X	12.75V	VCC	Data Out
Program Inhibit	V _{IH}	V _{IH}	X	X	X	12.75V	6.25V	Hi-Z
Manufacturer Code ⁽³⁾	V _{IL}	V _{IL}	V _{IL}	V _{IL}	V _{ID}	VCC	VCC	37H
Device Code ⁽³⁾	V _{IL}	V _{IL}	V _{IH}	V _{IL}	V _{ID}	VCC	VCC	8DH
Continuation Code ⁽³⁾	V _{IL}	V _{IL}	V _{IL}	V _{IH}	V _{ID}	VCC	VCC	7FH

Notes:

1. X = Either V_{IH} or V_{IL}.
2. V_{ID} = 12V ± 0.5V.
3. A2 ~ A8 = A10 ~ A14 = V_{IL} (For auto identification)
4. VCC = 5V ± 5%

Functional Description

Read Mode

The A275308 has two control functions, both of which must be logically active in order to obtain data at the outputs. \overline{CE} is the power control and should be used for device selection. \overline{OE} is the output control and should be used to data to the output pins, which is independent of device selection. Assuming that addresses are stable, address access time (t_{AA}) is equal to the delay from \overline{CE} to output (t_{cE}). Data is available at the output after a delay (t_{oE}) from the falling edge of \overline{OE} , as long as \overline{CE} has been low and the addresses have been stable for at least $t_{acc} - t_{oE}$.

Standby Mode

The A275308 has a standby mode which reduces the active current from 30mA to 100 μ A. The A275308 is placed in the standby mode by applying a CMOS high signal to \overline{CE} . When in the standby mode, the output are in a high impedance state, independent of the \overline{OE} .

Absolute Maximum Ratings*

Ambient Operating Temperature (T_A)	-10°C to +85°C
Storage Temperature Plastic Package (T_{STG})	-55°C to 125°C
Applied Input Voltage (V_i):	
All Pins Except A9, VPP and VCC	-0.6V to VCC + 0.6V
A9, VPP	-0.6V to 13.5V
VCC	-0.6V to 7.0V
Output Voltage (V_o)	-0.6V to 7.0V (Note 1)

Notes:

1. During voltage transitions, the input may undershoot GND to -2.0V for periods less than 20 ns. Maximum DC voltage on input and I/O may overshoot to VCC + 2.0V for periods less than 20 ns.
2. When transitions, A9 and VPP may undershoot GND to -2.0V for periods less than 20 ns. Maximum DC input voltage on A9 and VPP is +13.5V which may overshoot to 14.0V for period less than 20 ns.

Auto Identify Mode

The auto identify mode allows the reading out of a binary code from an EPROM that will identify its manufacturer and type. This mode is intended for use by programming equipment for the purpose of automatically matching the device to be programmed with its corresponding programming algorithm.

To activate the mode, the programming equipment must apply 12.0V \pm 0.5V on address line A9 of the A275308. Three identification code can be read from data output pin by toggling A0 and A1. The Other addresses must be held at V_{IL} during this mode. Byte 0 (with A0 at V_{IL} , A1 at V_{IL}) represents the manufacturer code which is 37H. Byte 1 and Byte 2 represent the device code and continuation code, which is 8DH and 7FH respectively. All identifiers for these codes will possess odd parity, with MSB (IO7) defined the parity bit.

*Comments

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to this device. These are stress ratings only. Functional operation of this device at these or any other conditions above those indicated in the operational sections of this specification is not implied or intended. Exposure to the absolute maximum rating conditions for extended periods may affect device reliability.

Read Mode DC Electrical Characteristics ($T_a = 0^\circ\text{C}$ to 70°C , $V_{CC} = 5\text{V} \pm 10\%$, $V_{PP} = V_{CC}$)

Symbol	Parameter	Min.	Max.	Unit	Conditions
V_{OH}	Output High Voltage	2.4		V	$I_{OH} = -400\mu\text{A}$
V_{OL}	Output Low Voltage		0.4	V	$I_{OL} = 2.1\text{mA}$
V_{IH}	Input High Voltage	2.0	$V_{CC} + 0.5$	V	
V_{IL}	Input Low Voltage	-0.5	0.8	V	
I_{LI}	Input Leakage Current	-1	+1	μA	$V_{CC} = \text{max.}$ $V_{in} = 0\text{V}$ to V_{CC}
I_{LO}	Output Leakage Current	-1	+1	μA	$V_{CC} = \text{max.}$ $V_{out} = 0\text{V}$ to V_{CC}
I_{CC}	V_{CC} Read Operating Current		30	mA	$V_{CC} = \text{max.}$ $\overline{CE} = V_{IL}$, $\overline{OE} = V_{IL}$ $I_{out} = 0\text{mA}$, at 5MHz
I_{SB}	V_{CC} Standby Current (TTL)		1	mA	$V_{CC} = \text{max.}$ $\overline{CE} = V_{IH}$
I_{SB1}	V_{CC} Standby Current (CMOS)		100	μA	$V_{CC} = \text{max.}$ $\overline{CE} = V_{CC} - 0.2\text{V}$
I_{PP}	V_{PP} Current During Read		10	μA	$\overline{CE} = \overline{OE} = V_{IL}$, $V_{PP} = V_{CC}$
I_{ID}	A9 Auto Select Current		100	μA	$A9 = V_{ID}$, $V_{CC} = \text{max.}$

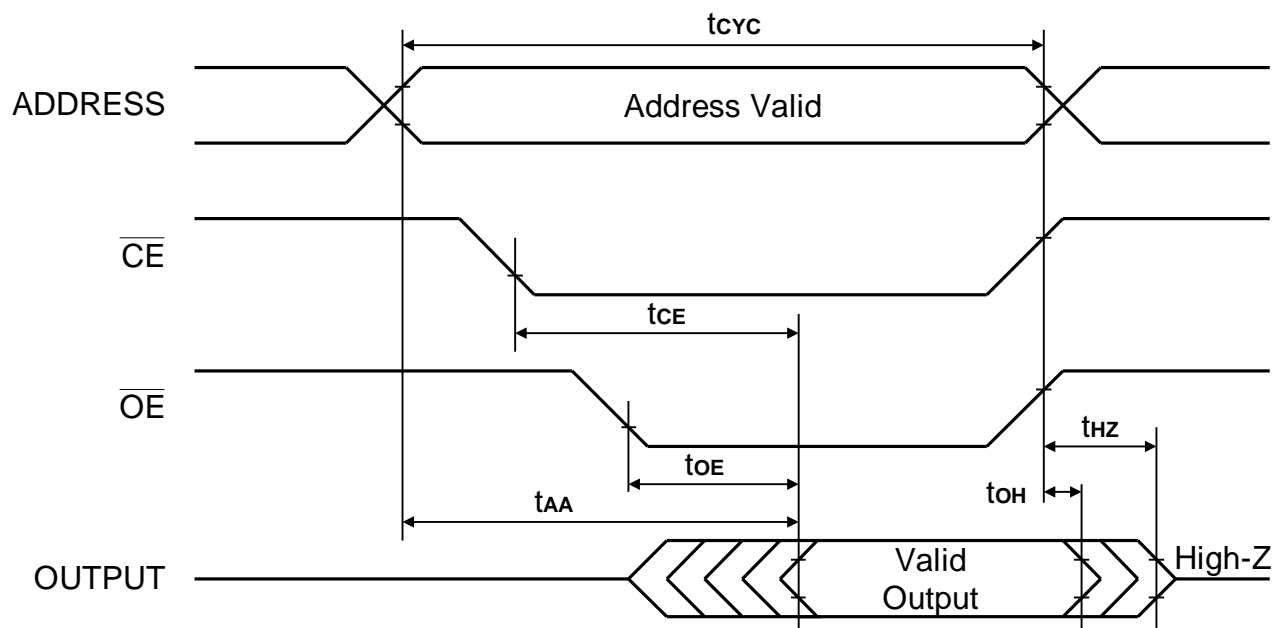
Capacitance ($T_a = 25^\circ\text{C}$, $f = 1.0\text{MHz}$)

Symbol	Parameter	Min.	Max.	Unit	Conditions
C_{IN}	Input Capacitance		8	pF	$V_{IN} = 0\text{V}$
C_{out}	Output Capacitance		8	pF	$V_{out} = 0\text{V}$

* These parameters are sampled and not 100% tested.

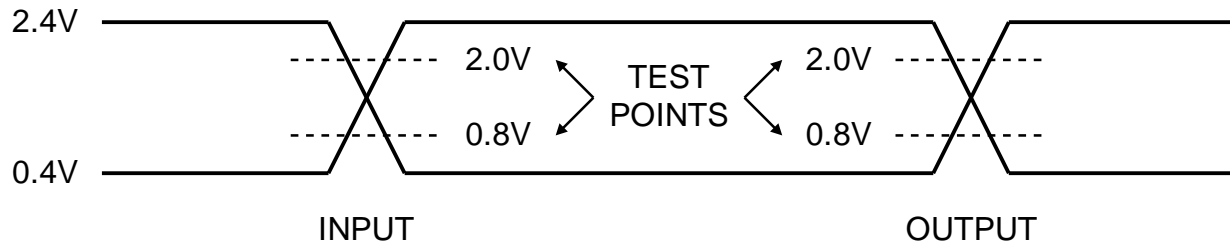
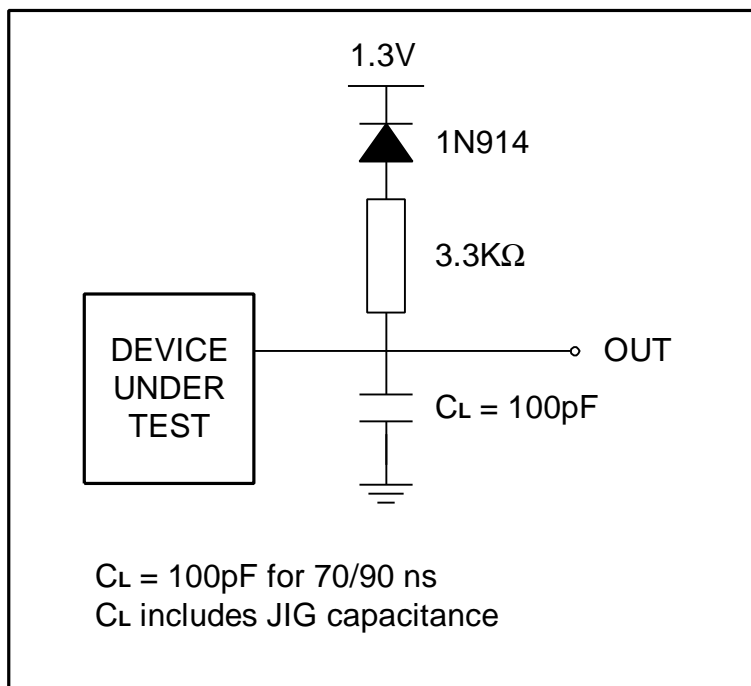
Read Mode AC Characteristics ($T_a = 0^\circ\text{C}$ to 70°C , $V_{CC} = 5V \pm 10\%$, $V_{PP} = V_{CC}$)

Symbol	Parameter	70ns		90ns		Unit
		Min.	Max.	Min.	Max.	
t_{cyc}	Cycle Time	70		90		ns
t_{AA}	Address Access Time		70		90	ns
t_{CE}	Chip Enable Access Time		70		90	ns
t_{OE}	Output Enable Access Time		35		40	ns
t_{OH}	Output Hold after Address, \overline{CE} or \overline{OE} , whichever Occurred First	0		0		ns
t_{HZ}	Output High Z Delay		20		25	ns

Read Mode Switching Waveforms


AC Measurement Conditions

for 70/90 ns ① Input Rise and Fall Times ≤ 10 ns
 Input Pulse Voltage: 0.4V to 2.4V
 Input and Output Timing Ref. Voltage: 0.8V to 2.0V


AC Testing Load Circuit


Programming and Program Verify

The programming flowchart is shown in Page 10.

The A275308 is shipped with all bits being set to "1". Programming causes relevant bits to be changed to "0". The programming mode is started by setting VCC to +6.25V and VPP to +12.75V, while \overline{CE} is at V_{IL} and \overline{OE} is at V_{IH} . Data to be programmed can be directly input in the 8 bit format through the data bus.

The write programming algorithm reduces programming time by using 100 μ s pulse followed by a byte verification to determine whether the byte has been successfully programmed. If the data does not pass the verification,

an additional pulse programming is applied for a maximum of 25 pulses. On completion of 1 byte programming and, The verified address is incremented. After the final address is completed, all bytes are verified again with VCC = 5.0 Volt.

Program Inhibit

This mode is used to program one of multiple A275308 whose \overline{OE} , VPP, VCC, address bus and data bus are connected in parallel. When programming is performed, other A275308 can be inhibited from being programmed by setting their \overline{CE} and \overline{OE} pins to V_{IH} .

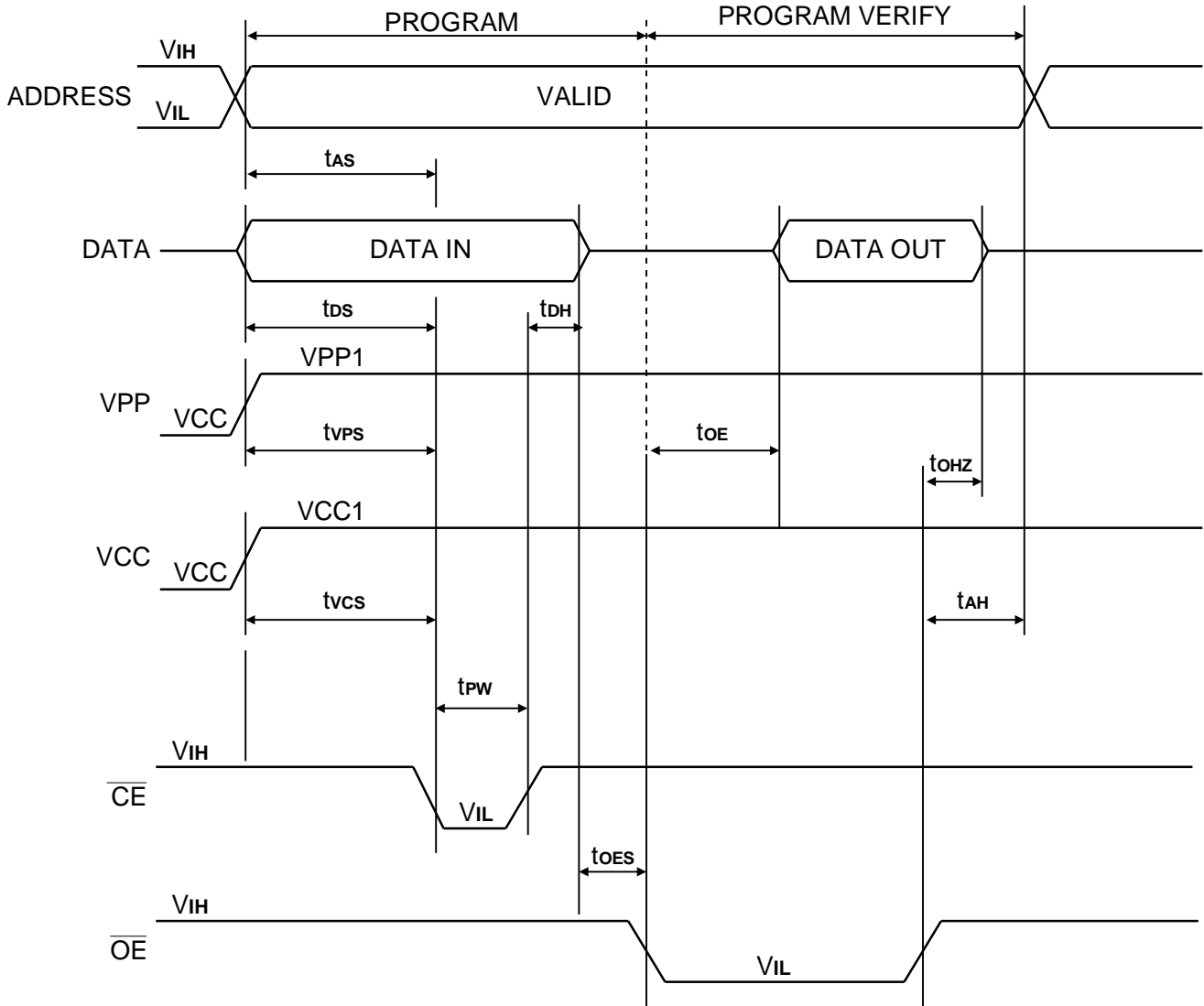
Programming Mode DC Characteristics (Ta = 0°C to 70°C, VCC = 6.25V \pm 0.25V, VPP = 12.75V \pm 0.25V)

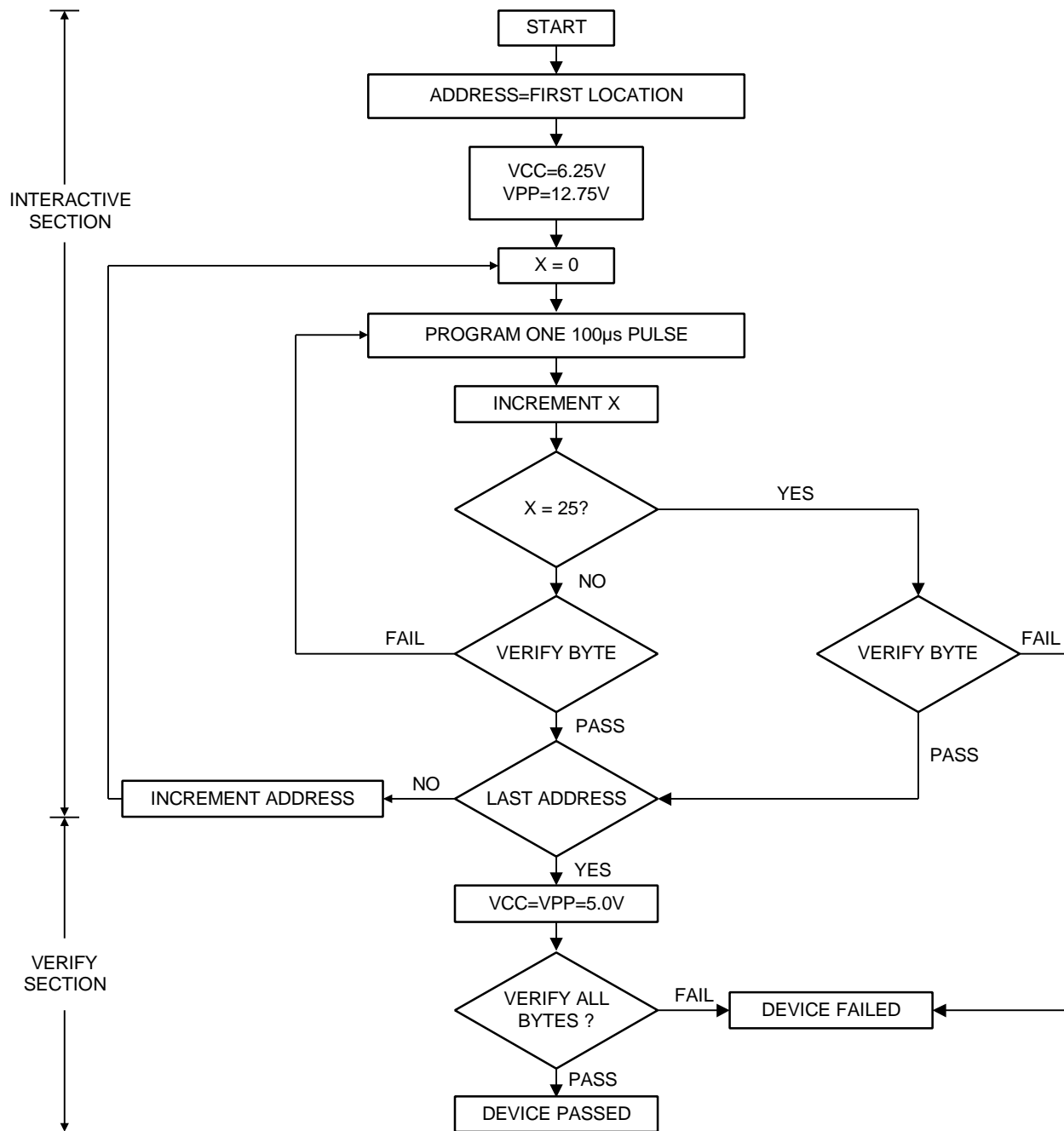
Symbol	Parameter	Min.	Max.	Unit	Test Conditions
V _{OH}	Output High Voltage	2.4		V	I _{OH} = -400 μ A
V _{OL}	Output Low Voltage		0.4	V	I _{OL} = 2.1mA
V _{IH}	Input High Voltage	2.0	VCC + 0.5	V	
V _{IL}	Input Low Voltage	-0.5	0.8	V	
I _I	Input Leakage Current	-1	+1	μ A	VCC = max. Vin = 0V to VCC
I _{CC}	VCC Current During Program		50	mA	
I _{PP}	VPP Current During Program		50	mA	$\overline{CE} = V_{IL}$
V _{ID}	A9 Auto Select Voltage	11.5	12.5	V	A9 = V _{ID}
VCC1	Programming Supply Voltage	6.0	6.5	V	
VPP1	Programming Voltage	12.5	13	V	

Note: VCC must be applied simultaneously or before VPP and removed simultaneously or after VPP.

Programming Mode AC Characteristics ($T_a = 0^\circ\text{C}$ to 70°C , $V_{CC} = 6.25\text{V} \pm 0.25\text{V}$, $V_{PP} = 12.75\text{V} \pm 0.25\text{V}$)

Symbol	Parameter	Min.	Max.	Unit
t _{AS}	Address Valid to Program Low	2		μs
t _{DS}	Input Valid to Program Low	2		μs
t _{VPS}	V _{PP} High to Program Low	2		μs
t _{VCS}	V _{CC} High to Program Low	2		μs
t _{PW}	Program Pulse Width	95	105	μs
t _{DH}	Program High to Input transition	2		μs
t _{OES}	$\overline{\text{OE}}$ Set up Time	2		μs
t _{OE}	$\overline{\text{OE}}$ Low to Output Valid		100	ns
t _{OHZ}	$\overline{\text{OE}}$ High to Output Hi-Z		130	ns
t _{AH}	$\overline{\text{OE}}$ High to Address Transition	0		ns
t _{CE}	Chip Enable Access Time	0	100	ns

Programming and Verify Mode AC Waveforms


Programming Flowchart


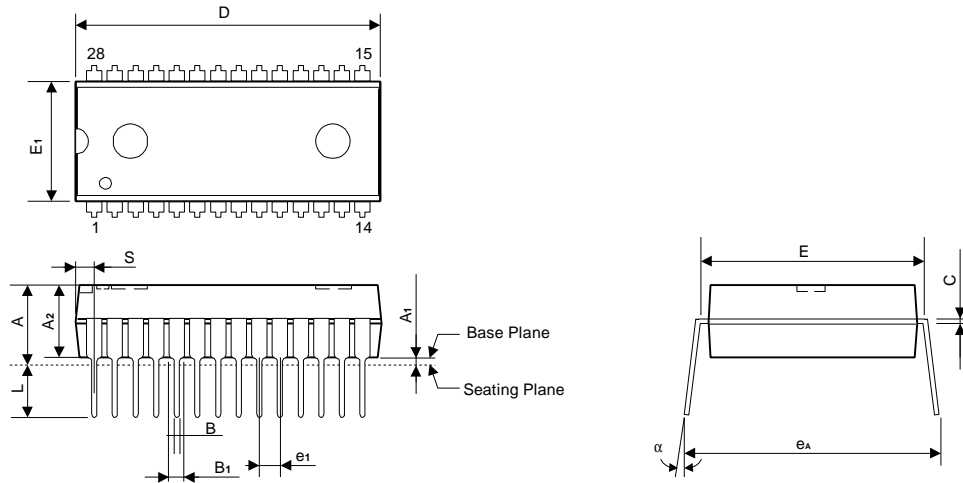


Ordering Information

Part No.	Access Time (ns)	Operating Current Max. (mA) at 5MHz	Standby Current Max. (μA)	Package
A275308-70	70	30	100	28Pin DIP
A275308L-70	70	30	100	32Pin PLCC
A275308-90	90	30	100	28Pin DIP
A275308L-90	90	30	100	32Pin PLCC

Package Information
P-DIP 28L Outline Dimensions

unit: inches/mm



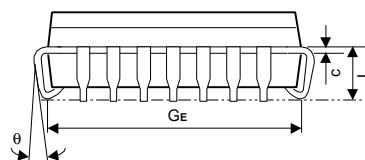
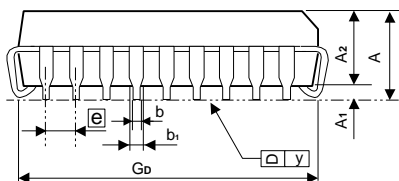
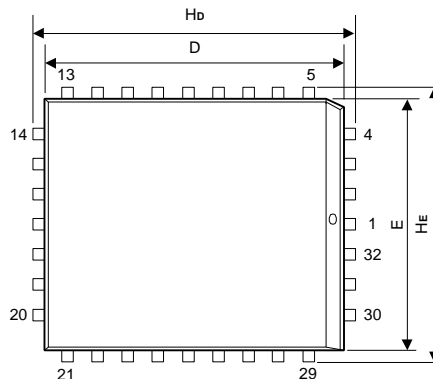
Symbol	Dimensions in inches			Dimensions in mm		
	Min	Nom	Max	Min	Nom	Max
A	-	-	0.210	-	-	5.33
A1	0.010	-	-	0.25	-	-
A2	0.150	0.155	0.160	3.81	3.94	4.06
B	0.016	0.018	0.022	0.41	0.46	0.56
B1	0.058	0.060	0.064	1.47	1.52	1.63
C	0.008	0.010	0.014	0.20	0.25	0.36
D	-	1.460	1.470	-	37.08	37.34
E	0.590	0.600	0.610	14.99	15.24	15.49
E1	0.540	0.545	0.550	13.72	13.84	13.97
e1	0.090	0.100	0.110	2.29	2.54	2.79
L	0.120	0.130	0.140	3.05	3.30	3.56
α	0°	-	15°	0°	-	15°
eA	0.630	0.650	0.670	16.00	16.51	17.02
S	-	-	0.090	-	-	2.29

Notes:

1. The maximum value of dimension D includes end flash.
2. Dimension E1 does not include resin fins.
3. Dimension S includes end flash.

Package Information
PLCC 32L Outline Dimension

unit: inches/mm



Symbol	Dimensions in inches			Dimensions in mm		
	Min	Nom	Max	Min	Nom	Max
A	-	-	0.134	-	-	3.40
A1	0.0185	-	-	0.47	-	-
A2	0.105	0.110	0.115	2.67	2.80	2.93
b1	0.026	0.028	0.032	0.66	0.71	0.81
b	0.016	0.018	0.021	0.41	0.46	0.54
C	0.008	0.010	0.014	0.20	0.254	0.35
D	0.547	0.550	0.553	13.89	13.97	14.05
E	0.447	0.450	0.453	11.35	11.43	11.51
e	0.044	0.050	0.056	1.12	1.27	1.42
G _D	0.490	0.510	0.530	12.45	12.95	13.46
G _E	0.390	0.410	0.430	9.91	10.41	10.92
H _D	0.585	0.590	0.595	14.86	14.99	15.11
H _E	0.485	0.490	0.495	12.32	12.45	12.57
L	0.075	0.090	0.095	1.91	2.29	2.41
y	-	-	0.003	-	-	0.075
θ	0°	-	10°	0°	-	10°

Notes:

- Dimensions D and E do not include resin fins.
- Dimensions G_D & G_E are for PC Board surface mount pad pitch design reference only.